



















### **3. Conclusion**

We have demonstrated SC generation in 1 cm long CMOS compatible hydrogenated amorphous silicon waveguides. Using wide waveguides (up to 800 nm width) that provide very low dispersion, we demonstrated a spectral broadening greater than 550 nm around telecommunication wavelengths with a low on chip peak power of 4 W. Quite unexpectedly, we did not observe any optical degradation in the wider waveguides. These results highlight the potential of a-Si-H for integrated, on chip, non linear optics.

### **Acknowledgments**

The authors thank Stéphane Coen, Thibaut Sylvestre and Mathieu Chauvet for fruitful discussions. We acknowledge financial support by the FRS-FNRS and by the Inter-University Attraction Pole (IAP) project Photonics@be. Part of this work was carried out in the framework of the FP7-ERC projects MIRACLE and InSpectra.